



DMP31D7LFBQ

Product Summary

BV _{DSS}	Rds(on)	Ι _D T _A = +25°C
-30V	0.9Ω @ V _{GS} = -10V	-0.81 A
	1.7Ω @ V _{GS} = -4.5V	-0.58 A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Load Switch

P-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- 0.6mm² Footprint—Thirteen Times Smaller than SOT23
- Low Gate Threshold Voltage
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMP31D7LFBQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

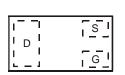
- Package: X1-DFN1006-3
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—NiPdAu over Copper Lead-Frame. Solderable per MIL-STD-202, Method 208 @
- Weight: 0.001 grams (Approximate)



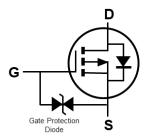
X1-DFN1006-3



Bottom View



Top View Internal Schematic



Equivalent Circuit

Ordering Information (Note 4)

Part Number	Baakaga	Marking Reel Size Tape Width Tape Pitch Packing				king	
Fait Nulliber	Package	Warking	(inches)	(mm)	(mm)	Qty.	Carrier
DMP31D7LFBQ-7B	X1-DFN1006-3	ĀN	7	8	2	10,000	Reel

Notes:

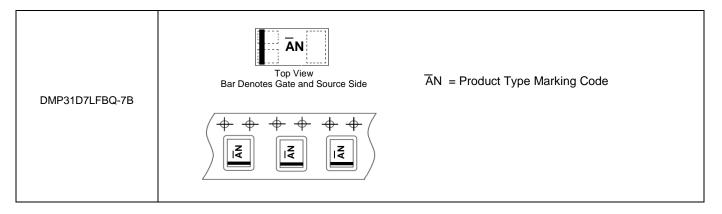
No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3).compliant.
 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit			
Drain-Source Voltage			Vdss	-30	V	
Gate-Source Voltage			V _{GSS}	±20	V	
Continuous Prain Current (Note 6) Vac. 10V	Steady	T _A = +25°C	1-	-0.81	٨	
Continuous Drain Current (Note 6) VGS = -10V	State	T _A = +70°C	ID	-0.64	A	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I _{DM}	-2.4	А	

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	0.53	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{OJA}	236	°C/W
Total Power Dissipation (Note 6)	PD	0.89	W
Thermal Resistance, Junction to Ambient (Note 6)	Reja	141	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

 Notes:
 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 25mm x 25mm square copper plate.



Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

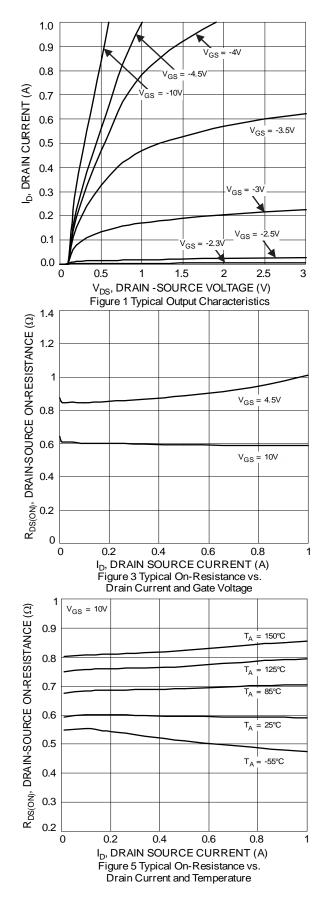
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)						-	
Drain-Source Breakdown Voltage	BVDSS	-30	—	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current TJ = +25°C	IDSS	_	_	-1	μA	$V_{DS} = -24V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	—	±10	μA	$V_{GS} = \pm 16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	-1	—	-2.6	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
Static Drain-Source On-Resistance	Descer		0.5	0.9	Ω	VGS = -10V, ID = -0.42A	
Static Drain-Source On-Resistance	Rds(on)		0.8	1.7		$V_{GS} = -4.5V, I_D = -0.2A$	
Diode Forward Voltage	V _{SD}	—	-0.8	-1.2	V	$V_{GS} = 0V, I_{S} = -0.23A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	19		pF		
Output Capacitance	Coss		16		рF	VDS = -15V, VGS = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	3		pF	1 = 1.00012	
Gate Resistance	Rg	—	729	—	Ω	$V_{DS} = V_{GS} = 0V$, f = 1.0MHz	
Total Gate Charge (V _{GS} = 4.5V)	Qg	—	0.36	_	nC	VGS = -4.5V, VDS = -10V, I _D = -250mA	
Gate-Source Charge	Q _{gs}	—	0.1	—	nC		
Gate-Drain Charge	Q _{gd}	_	0.1	—	nC		
Turn-On Delay Time	tD(ON)	_	30	—	ns	VDD = -10V, VGS = -4.5V,	
Turn-On Rise Time	t _R	_	74		ns		
Turn-Off Delay Time	tD(OFF)	_	28		ns	$R_L = 47\Omega, R_G = 10\Omega,$	
Turn-Off Fall Time	tF	_	31		ns	– I _D = -200mA	

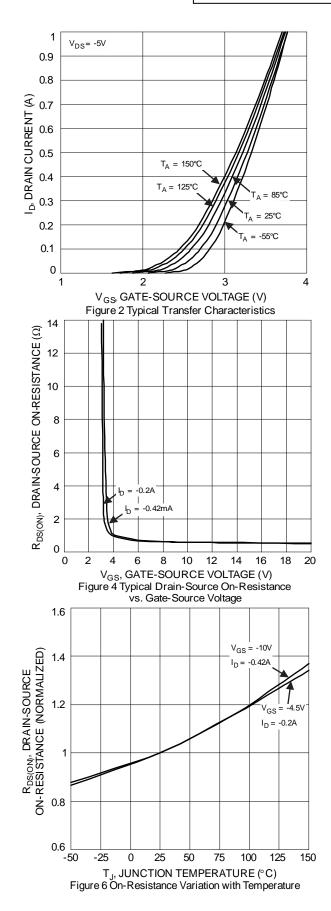
Notes: 7. Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to product testing.

DMP31D7LFBQ Document number: DS43055 Rev. 2 - 2

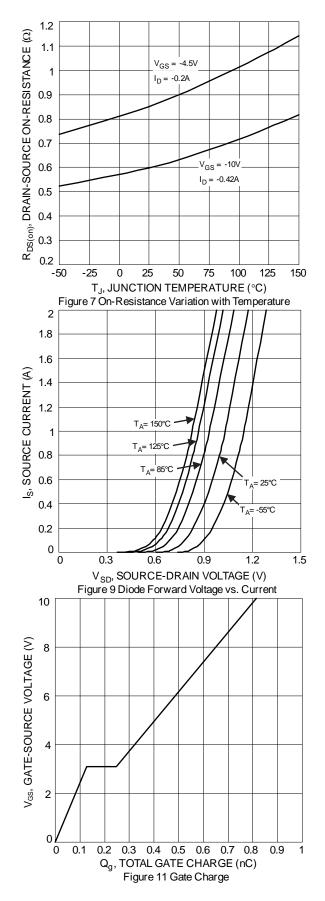


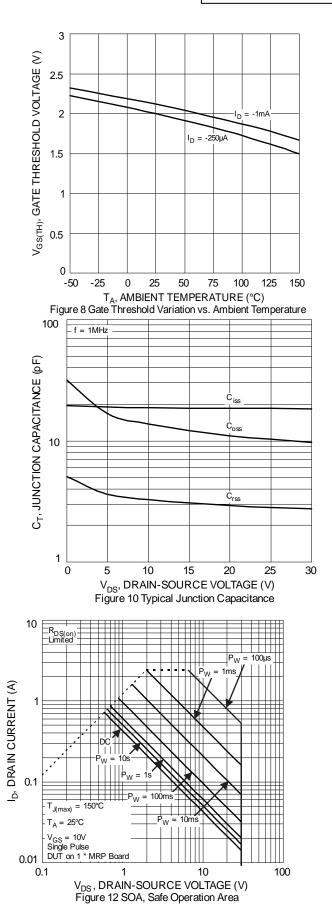
DMP31D7LFBQ



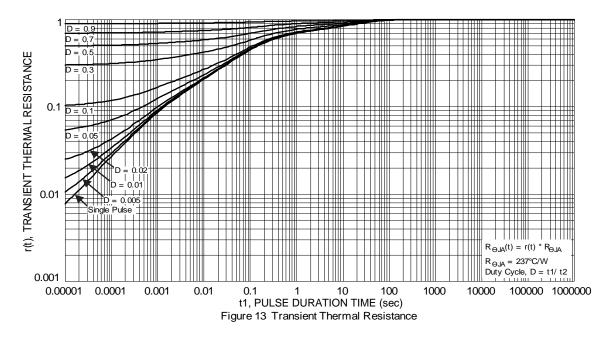










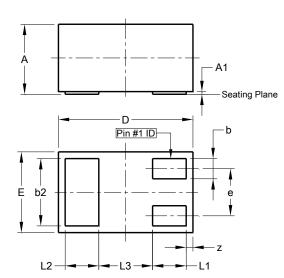




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

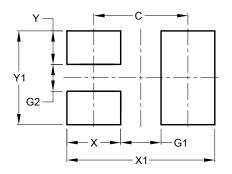




X1-DFN1006-3						
Dim	Min	Max	Тур			
Α	0.47	0.53	0.50			
A1	0.00	0.05	0.03			
b	0.10	0.20	0.15			
b2	0.45	0.55	0.50			
D	0.95	1.075	1.00			
E	0.55	0.675	0.60			
е	-	-	0.35			
L1	0.20	0.30	0.25			
L2	0.20	0.30	0.25			
L3	-	-	0.40			
Z	0.02	0.08	0.05			
All D	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



X1-DFN1006-3

Dimensions	Value (in mm)
С	0.70
G1	0.30
G2	0.20
Х	0.40
X1	1.10
Y	0.25
Y1	0.70



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